## PNP Silicon Digital Transistor

- Built in bias resistor $\left(R_{1}=1 \mathrm{k} \Omega, R_{2}=10 \mathrm{k} \Omega\right)$
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101


| Type | Marking | Pin Configuration |  |  | Package |
| :--- | :--- | :--- | :--- | :--- | :--- |
| BCR573 | XHs | $1=\mathrm{B}$ | $2=\mathrm{E}$ | $3=\mathrm{C}$ | SOT23 |

## Maximum Ratings

| Parameter | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Collector-emitter voltage | $V_{\text {CEO }}$ | 50 | V |
| Collector-base voltage | $V_{\text {CBO }}$ | 50 |  |
| Input forward voltage | $V_{\text {i }}$ (fwd) | 12 |  |
| Input reverse voltage | $V_{i(r e v)}$ | 5 |  |
| Collector current | $I_{C}$ | 500 | mA |
| Total power dissipation$T_{\mathrm{S}} \leq 79^{\circ} \mathrm{C}$ | $P_{\text {tot }}$ | 330 | mW |
| Junction temperature | $T_{j}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $T_{\text {stg }}$ | -65 ... 150 |  |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
| :--- | :--- | :--- | :--- |
| Junction - soldering point ${ }^{1}$ ) | $R_{\text {thJS }}$ | $\leq 215$ | K/W |

[^0]Electrical Characteristics at $T_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise specified

| Parameter | Symbol | Values |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | min. | typ. | max. |  |
| DC Characteristics |  |  |  |  |  |
| Collector-emitter breakdown voltage $I_{\mathrm{C}}=100 \mu \mathrm{~A}, I_{\mathrm{B}}=0$ | $V_{\text {(BR)CEO }}$ | 50 | - | - | V |
| Collector-base breakdown voltage $I_{\mathrm{C}}=10 \mu \mathrm{~A}, I_{\mathrm{E}}=0$ | $V_{\text {(BR)CBO }}$ | 50 | - | - |  |
| Collector-base cutoff current $V_{C B}=50 \mathrm{~V}, I_{\mathrm{E}}=0$ | $I_{\text {CBO }}$ | - | - | 100 | nA |
| Emitter-base cutoff current $V_{\mathrm{EB}}=5 \mathrm{~V}, I_{\mathrm{C}}=0$ | IEBO | - | - | 0.72 | mA |
| DC current gain- $I_{\mathrm{C}}=50 \mathrm{~mA}, V_{\mathrm{CE}}=5 \mathrm{~V}$ | $h_{\text {FE }}$ | 70 | - | - | - |
| Collector-emitter saturation voltage ${ }^{1)}$ $I_{C}=50 \mathrm{~mA}, I_{\mathrm{B}}=2.5 \mathrm{~mA}$ | $V_{\text {CEsat }}$ | - | - | 0.3 | V |
| Input off voltage $I_{\mathrm{C}}=100 \mu \mathrm{~A}, V_{\mathrm{CE}}=5 \mathrm{~V}$ | $V_{i(\text { (off })}$ | 0.3 | - | 1 |  |
| Input on voltage $I_{\mathrm{C}}=10 \mathrm{~mA}, V_{\mathrm{CE}}=0.3 \mathrm{~V}$ | $V_{i(0 n)}$ | 0.4 | - | 1.4 |  |
| Input resistor | $R_{1}$ | 0.7 | 1 | 1.3 | k $\Omega$ |
| Resistor ratio | $R_{1} / R_{2}$ | 0.09 | 0.1 | 0.11 | - |
| AC Characteristics |  |  |  |  |  |
| Transition frequency $I_{\mathrm{C}}=50 \mathrm{~mA}, V_{\mathrm{CE}}=5 \mathrm{~V}, f=100 \mathrm{MHz}$ | $f_{\text {T }}$ | - | 150 | - | MHz |

[^1]BCR573

DC current gain $h_{\text {FE }}=f\left(I_{\mathrm{C}}\right)$
$V_{C E}=5 \mathrm{~V}$ (common emitter configuration)


Input on Voltage $V_{i_{(o n)}}=f\left(I_{C}\right)$
$V_{C E}=0.3 \mathrm{~V}$ (common emitter configuration)


## Collector-emitter saturation voltage

$V_{\text {CEsat }}=f\left(I_{\mathrm{C}}\right), h_{\text {FE }}=20$


Input off voltage $V_{i(\text { off })}=f\left(l_{\mathrm{C}}\right)$
$V_{C E}=5 \mathrm{~V}$ (common emitter configuration)


Total power dissipation $P_{\text {tot }}=f\left(T_{\mathrm{S}}\right)$


Permissible Pulse Load
$P_{\text {totmax }} / P_{\text {totDC }}=f\left(t_{\mathrm{p}}\right)$


Permissible Pulse Load $R_{\text {thJS }}=f\left(t_{\mathrm{p}}\right)$


Package Outline


1) Lead width can be 0.6 max. in dambar area

Foot Print


Marking Layout (Example)


## Standard Packing

Reel $\varnothing 180 \mathrm{~mm}=3.000$ Pieces/Reel
Reel $\varnothing 330 \mathrm{~mm}=10.000$ Pieces/Reel


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[^0]:    ${ }^{1}$ For calculation of $R_{\text {thJA }}$ please refer to Application Note ANO77 (Thermal Resistance Calculation)

[^1]:    ${ }^{1}$ Pulse test: $\mathrm{t}<300 \mu \mathrm{~s}$; $\mathrm{D}<2 \%$

